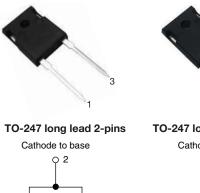
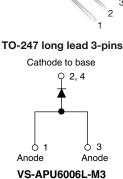
www.vishay.com

Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®

3





VS-EPU6006L-M3

Cathode

ტ

Anode

3

| PRODUCT SUMMARY | | | | | | |
|----------------------------------|--------------------------|--|--|--|--|--|
| Package | TO-247 long lead 2 pins, | | | | | |
| Fackage | TO-247 long lead 3 pins | | | | | |
| I _{F(AV)} | 60 A | | | | | |
| V _R | 600 V | | | | | |
| V _F at I _F | 1.05 V | | | | | |
| t _{rr} typ. | 32 ns | | | | | |
| T _J max. | 175 °C | | | | | |
| Diode variation | Single die | | | | | |

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification



[•] Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

VS-EPU60/VS-APU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | |
| Repetitive peak reverse voltage | V _{RRM} | | 600 | V | | | |
| Average rectified forward current in DC | I _{F(AV)} | T _C = 116 °C | 60 | ٨ | | | |
| Single pulse forward current | I _{FSM} | T _C = 25 °C | 600 | A | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -55 to +175 | °C | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-------------------------------------|---|------|------|-------|----|
| PARAMETER | SYMBOL | TEST CONDITIONS | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 600 | - | - | |
| Forward voltage | V _F | I _F = 60 A | - | 1.2 | 1.5 | V |
| | | $I_F = 60 \text{ A}, \text{T}_\text{J} = 125 \ ^\circ\text{C}$ | - | 1.1 | 1.3 | |
| | | I _F = 60 A, T _J = 175 °C | - | 1.05 | 1.2 | |
| | | V _R = V _R rated | - | 0.2 | 30 | |
| Reverse leakage current | I _R | $T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$ | - | - | 200 | μΑ |
| Junction capacitance | CT | V _R = 600 V | - | 38 | - | pF |

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Vishay Semiconductors

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | |
|---|------------------|--|---|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 20$ | 00 A/µs, V _R = 30 V | - | 32 | - | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 110 | - | ns | |
| | | T _J = 125 °C | I _F = 60 A dI _F /dt = 200 A/µs V _R = 200 V | - | 200 | - | | |
| Peak recovery current | I _{RRM} | T _J = 25 °C | | - | 10 | - | ^ | |
| | | T _J = 125 °C | | - | 19 | - | A | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 530 | - | | |
| | Q _{rr} | T _J = 125 °C | | - | 1900 | - | nC | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|--|----------|------|-------------|-----------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C |
| Thermal resistance, junction to case | R _{thJC} | | - | - | 0.65 | |
| Thermal resistance, junction to ambient | R _{thJA} | Typical socket mount | - | - | 70 | °C/W |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | - |
| Weight | | | - | 6 | - | g |
| Weight | | | - | 0.21 | - | oz. |
| Mounting torque | | | 6 (5) | - | 1.2 (10) | kgf. cm (lbf ⋅ in) |
| Marking dayling | | Case style TO-247 long lead 2 pins | EPU6006L | | | - |
| Marking device | | Case style TO-247 long lead 3 pins | | APU | 6006L | |



Vishay Semiconductors

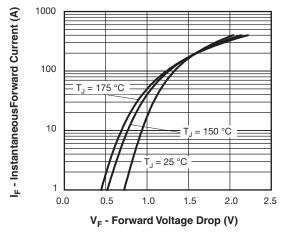


Fig. 1 - Typical Forward Voltage Drop Characteristics

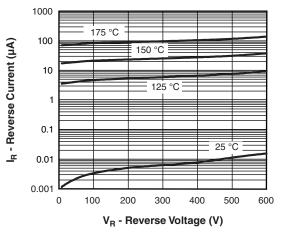


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

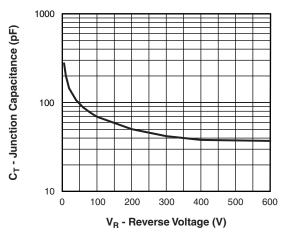


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

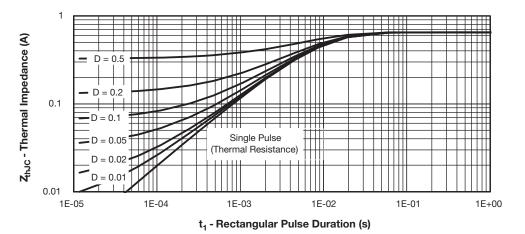
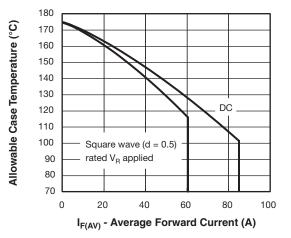


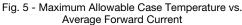
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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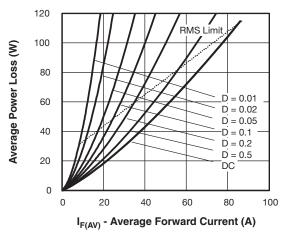


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

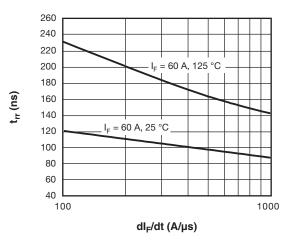


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

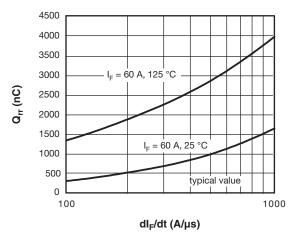
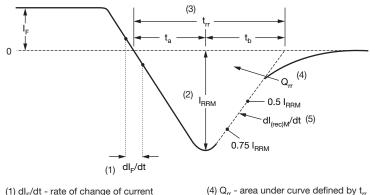


Fig. 8 - Typical Stored Charge vs. dl_F/dt



Vishay Semiconductors



- (1) dl_F/dt rate of change of current through zero crossing
- (4) Q_m area under curve defined by t_n and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

 $Q_{rr} = \frac{t_{rr} \times I_{BBM}}{2}$

(5) dl_{(rec)M}/dt - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

| Device code |
|-------------|
|-------------|

| e | VS- | Е | Ρ | U | 60 | 06 | L | -M3 | |
|---|--|----------------------------|-----------------------------|-------------|-----------|-------|---|-----|--|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | |
| | 1 - | Visł | nay Sem | niconduc | ctors pro | oduct | | | |
| | Circuit configuration: A = single diode 3-pin E = single diode 2-pin | | | | | | | | |
| | 3 - | P = | P = TO-247 | | | | | | |
| | 4 - | - U = | U = ultrafast recovery time | | | | | | |
| | 5 - | - Current code (60 = 60 A) | | | | | | | |
| | 6 - | - Volt | Voltage code (06 = 600 V) | | | | | | |
| | 7 - | L = | long lea | d | | | | | |
| | 8 - | Env | ironmer | ntal digit: | : | | | | |

-M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--|----|-----|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTI | | | | | | |
| VS-EPU6006L-M3 | 30 | 300 | Antistatic plastic tube | | | |
| VS-APU6006L-M3 | 30 | 300 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--------------------------|--|--|--|
| Dimensione | www.vishay.com/doc?95599 | | | | |
| Dimensions | TO-247AC 2-pin LL | www.vishay.com/doc?95598 | | | |
| Port marking information | TO-247 3-pin LL | www.vishay.com/doc?95593 | | | |
| Part marking information | TO-247 2-pin LL | www.vishay.com/doc?95592 | | | |

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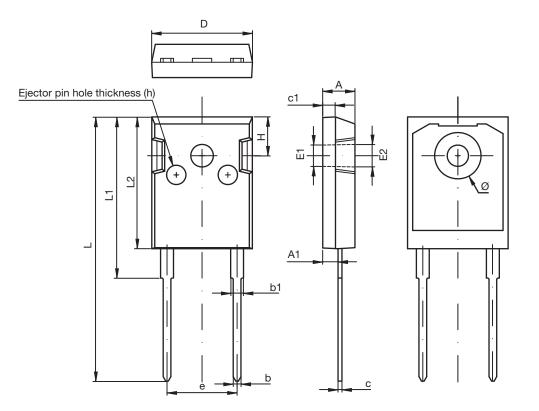


Vishay Semiconductors

TO-247 2 Pin Long Lead

DIMENSIONS in millimeters

ISHAY



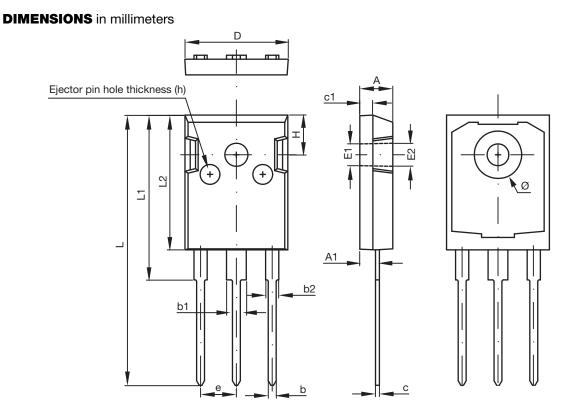
| SYMBOL | DIMENSIONS | N MILLIMETERS | DIMENSION | S IN INCHES |
|--------|-------------|---------------|------------|-------------|
| STMDOL | MIN. | MAX. | MIN. | MAX. |
| A | 4.850 | 5.150 | 0.191 | 0.200 |
| A1 | 2.200 | 2.600 | 0.087 | 0.102 |
| b | 1.000 | 1.400 | 0.039 | 0.055 |
| b1 | 1.800 | 2.200 | 0.071 | 0.087 |
| С | 0.500 | 0.700 | 0.020 | 0.028 |
| c1 | 1.900 | 2.100 | 0.075 | 0.083 |
| D | 15.450 | 15.750 | 0.608 | 0.620 |
| E1 | 3.500 Ref. | | 0.138 | 3 Ref. |
| E2 | 3.60 | 00 Ref. | 0.142 Ref. | |
| L | 40.900 | 41.300 | 1.610 | 1.626 |
| L1 | 24.800 | 25.100 | 0.976 | 0.988 |
| L2 | 20.300 | 20.600 | 0.799 | 0.811 |
| Ø | 7.100 | 7.300 | 0.280 | 0.287 |
| е | 10.900 Тур. | | 0.429 Тур. | |
| н | 5.980 Тур. | | 0.235 Typ. | |
| h | 0.000 | 0.300 | 0.000 | 0.012 |

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TO-247 3 Pin Long Lead



| OVMDOL | DIMENSIONS | IN MILLIMETERS | DIMENSION | S IN INCHES | |
|--------|------------|----------------|------------|-------------|--|
| SYMBOL | MIN. | MAX. | MIN. | MAX. | |
| А | 4.850 | 5.150 | 0.191 | 0.200 | |
| A1 | 2.200 | 2.600 | 0.087 | 0.102 | |
| b | 1.000 | 1.400 | 0.039 | 0.055 | |
| b1 | 2.800 | 3.200 | 0.110 | 0.126 | |
| b2 | 1.800 | 2.200 | 0.071 | 0.087 | |
| С | 0.500 | 0.700 | 0.020 | 0.028 | |
| c1 | 1.900 | 2.100 | 0.075 | 0.083 | |
| D | 15.450 | 15.750 | 0.608 | 0.620 | |
| E1 | 3.50 | 00 Ref. | 0.138 Ref. | | |
| E2 | 3.60 | 00 Ref. | 0.142 | ? Ref. | |
| L | 40.900 | 41.300 | 1.610 | 1.626 | |
| L1 | 24.800 | 25.100 | 0.976 | 0.988 | |
| L2 | 20.300 | 20.600 | 0.799 | 0.811 | |
| Ø | 7.100 | 7.300 | 0.280 | 0.287 | |
| е | 5.450 Тур. | | 0.215 | Тур. | |
| Н | 5.980 Тур. | | 0.235 Typ. | | |
| h | 0.000 | 0.300 | 0.000 | 0.012 | |

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 RRE02VS6SGTR
 067907F
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 70HF40
 T85HFL60S02
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 NTE6002
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